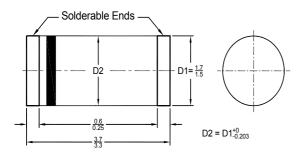


# **SM5817 THRU SM5819**

# SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS VOLTAGE RANG E: 20 --- 40 VCURRENT: 1.0 A

## **DO-213AA**



Dimensions in millimeters

### **FEATURES**

- Metal-Semiconductor junction with guard ring
- ♦ Low forward voltage drop,low switching losses
- ♦ High surge capability
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ♦ The plastic material carries U/L recognition 94V-0

#### **MECHANICAL DATA**

- ♦ Case: MiniMELF (DO-213AA), molded plastic body
- Polarity: Color band denotes cathode end

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

MDD Catalog Number		LM5817	LM5818	LM5819	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	20	30	40	V
Maximum RMS voltage	$V_{RMS}$	14	21	28	V
Maximum DC blocking voltage	$V_{DC}$	20	30	40	V
Maximum average forw ard rectified current  @T <sub>A</sub> =90°C	I <sub>F(AV)</sub>		1.0		А
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load	I <sub>FSM</sub>		25		А
Maximum instantaneous forward voltage @ 1.0A (Note 1) @ 3.0A	V <sub>F</sub>	0.45 0.75	0.55 0.875	0.60 0.90	V
Maximum reverse current $@T_A=25^{\circ}C$ at rated DC blocking voltage $@T_A=100^{\circ}C$	I <sub>R</sub>	0.5 10.0			mA
Typical junction capacitance (Note2)	$C_J$	110			pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	75			°C/W
Operating junction temperature range	$T_J$	- 55 + 125			$^{\circ}$ C
Storage temperature range	T <sub>STG</sub>	- 55 <b>+</b> 150			$^{\circ}\!\mathbb{C}$

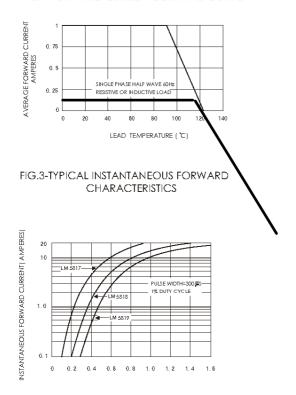
NOTE: 1. Pulse test :  $300\,\mu$  s pulse width,1% duty cycle.

- 2. Measured at  $1.0 \mathrm{MH_{Z}}$  and applied reverse voltage of  $4.0 \mathrm{V}$  DC.
- 3. Thermal resistance junction to ambient, vertical PC board mounting, 0.5" (12.7mm) lead length.

# MDD ELECTRONIC

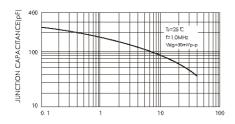
# **RATINGS AND CHARACTERISTIC CURVES LM5817 THRU LM5819**

#### FIG.1-FORWARD CURRENT DERATING CURVE

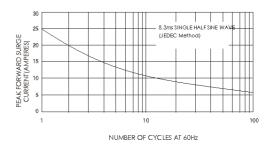


INSTANTANEOUS FORWARD VOLTAGE (VOLTS)

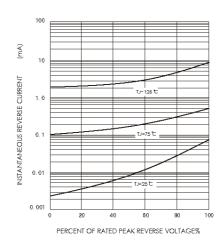
# FIG.5-TYPICAL JUNCTION CAPACITANCE



# FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



#### FIG.4-TYPICAL REVERSE CHARACTERISTICS



**MDD ELECTRONIC**